74AUP2G132

Low-power dual 2-input NAND Schmitt trigger Rev. 8 — 3 July 2017

Product data sheet

General description

The 74AUP2G132 provides the dual 2-input NAND Schmitt trigger function which accepts standard input signals. They can transform slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H.

Features and benefits 2

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5 000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1 000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

Applications

- · Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator



4 Ordering information

Table 1. Ordering information

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74AUP2G132DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1						
74AUP2G132GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm	SOT833-1						
74AUP2G132GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm	SOT1089						
74AUP2G132GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm	SOT902-2						
74AUP2G132GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm	SOT1116						
74AUP2G132GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm	SOT1203						
74AUP2G132GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 x 0.8 x 0.35 mm	SOT1233						

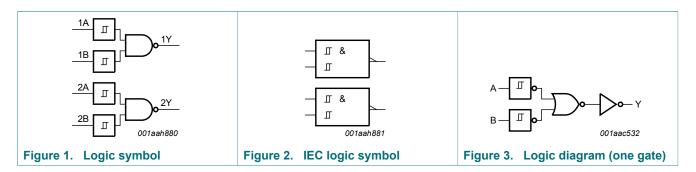
5 Marking

Table 2. Marking codes

Type number	Marking code ^[1]
74AUP2G132DC	aE2
74AUP2G132GT	aE2
74AUP2G132GF	аЕ
74AUP2G132GM	aE2
74AUP2G132GN	аЕ
74AUP2G132GS	аЕ
74AUP2G132GX	аЕ

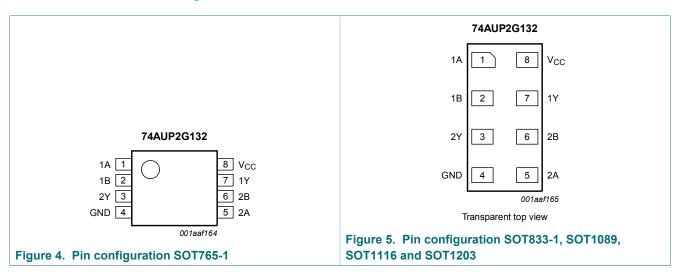
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

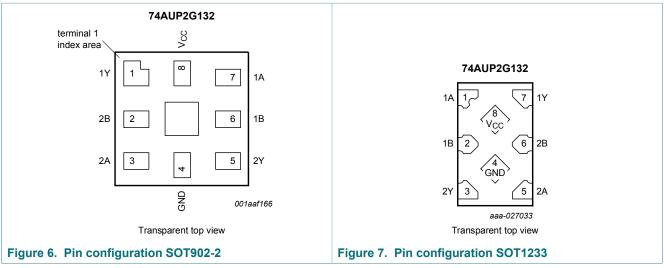
6 Functional diagram



7 Pinning information

7.1 Pinning





74AUP2G132

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7.2 Pin description

Table 3. Pin description

Symbol	Pin	Pin		
	SOT765-1, SOT833-1, SOT1089, SOT1116, SOT1203 and SOT1233	SOT902-2		
1A, 2A	1, 5	7, 3	data input	
1B, 2B	2, 6	6, 2	data input	
GND	4	4	ground (0 V)	
1Y, 2Y	7, 3	1, 5	data output	
V _{CC}	8	8	supply voltage	

8 Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input		Output
nA	nB	nY
L	L	Н
L	н	Н
Н	L	Н
Н	Н	L

9 Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
V _I	input voltage		[1]	-0.5	+4.6	V
lok	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

 ^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 [2] For VSSOP8 packages: above 110 °C the value of P_{tot} derates linearly with 8.0 mW/K.

10 Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
V _O	output voltage	Active mode	0	V_{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

^[2] For VSSOP8 packages: above 110 °C the value of P_{tot} derates linearly with 8.0 mW/K. For XSON8 and XQFN8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K. For X2SON8 package: above 118 °C the value of P_{tot} derates linearly with 7.7 mW/K.

11 Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		$I_{\rm O}$ = -2.3 mA; $V_{\rm CC}$ = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_{\rm O}$ = 20 μ A; $V_{\rm CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_1 or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μA
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μA
C _I	input capacitance	$V_I = GND \text{ or } V_{CC}$; $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	1.1	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C	1				
V_{OH}	HIGH-level output voltage	HIGH-level output voltage $V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V		-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.7 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.33	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.45	V
Iį	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_I or V_O = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}^{[1]}$	-	-	50	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +125 °C				1	
V_{OH}	HIGH-level output voltage	HIGH-level output voltage $V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.36	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.50	V
Iį	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_I or V_O = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μΑ
Δl _{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μA

^[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

12 Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 9.

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	-40 °C to	+125 °C	Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 pF						,			
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 [2]							
		V _{CC} = 0.8 V	-	22.5	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.3	13.4	2.4	15.1	16.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.2	1.9	9.7	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.9	8.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.2	5.3	1.5	6.2	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.9	4.7	1.4	5.6	6.2	ns
C _L = 10 p	F			'			1		
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 [2]							
		V _{CC} = 0.8 V	-	26.1	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.2	15.4	2.7	17.3	19.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	5.2	9.3	2.2	11.0	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.5	7.5	2.0	9.0	9.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	6.1	1.8	7.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	5.5	1.8	6.5	7.2	ns
C _L = 15 p	F								
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 [2]							
		V _{CC} = 0.8 V	-	29.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	8.0	17.2	3.0	19.4	21.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.8	5.8	10.4	2.5	12.3	13.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.0	8.3	2.3	10.0	11.0	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.2	6.7	2.1	7.9	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.9	6.1	2.0	7.3	8.0	ns

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T_{amb} = -40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 30 p	F						<u>'</u>		
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 [2]							
		V _{CC} = 0.8 V	-	39.9	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	27.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	14.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	11.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	10.1	ns
C _L = 5 pF	, 10 pF, 15 pF and 3	0 pF		'	•	'			
C _{PD}	power dissipation	f_i = 1 MHz; V_I = GND to V_{CC} [3]							
	capacitance	V _{CC} = 0.8 V	-	2.6	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	pF

All typical values are measured at nominal V_{CC}. t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_0)$ where:

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

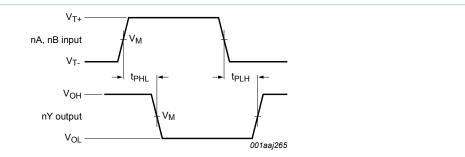
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $[\]Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1 Waveforms and test circuit



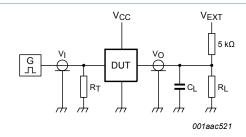
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 8. The data input (nA or nB) to output (nY) propagation delays

Table 9. Measurement points

Supply voltage	Output	Input				
V _{CC}	V _M	V _M	VI	$t_r = t_f$		
0.8 V to 3.6 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns		



Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Figure 9. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	2 x V _{CC}

[1] $R_L = 5 \text{ k}\Omega$ when measuring enable and disable times. $R_L = 1 \text{ M}\Omega$ when measuring propagation delays, setup and hold times and pulse width.

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13 Transfer characteristics

Table 11. Transfer characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 9.

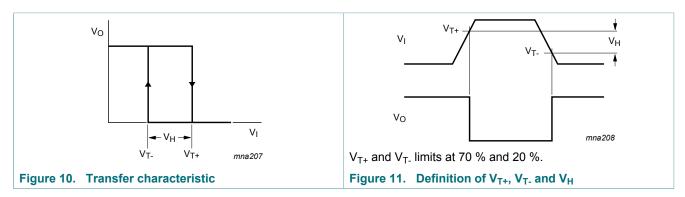
Symbol	Parameter	Conditions	T _{ar}	_{nb} = 25	°C	T _{amb} =	= -40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V _{T+} positive-going threshold voltage	see <u>Figure 10</u> and <u>Figure 11</u>								
		V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.62	V
		V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	2.32	V
V _{T-}	negative-going threshold voltage	see Figure 10 and Figure 11							
		V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	1.24	V
V _H hysteresis	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Figure 10</u> , <u>Figure 11</u> , <u>Figure 12</u> and <u>Figure 13</u>							
		V _{CC} = 0.8 V 0.07	-	0.50	0.07	0.50	0.50	V	
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	1.31	V

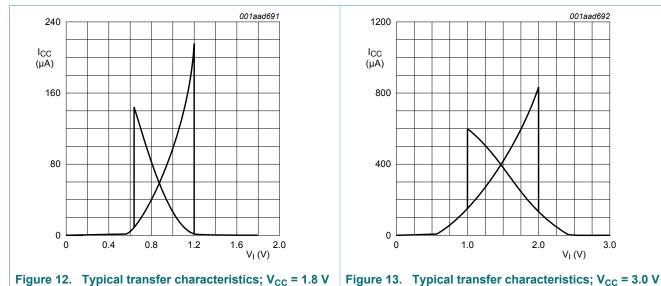
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3.0

Low-power dual 2-input NAND Schmitt trigger

13.1 Waveforms transfer characteristics





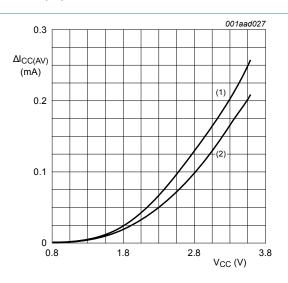
14 Application information

The slow input rise and fall times cause additional power dissipation which can be calculated using the following formula:

 $P_{add} = f_i x (t_r \times \Delta I_{CC(AV)} + t_f x \Delta I_{CC(AV)}) x V_{CC}$ where:

- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- $\Delta I_{CC(AV)}$ = average additional supply current (μA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Figure 14.

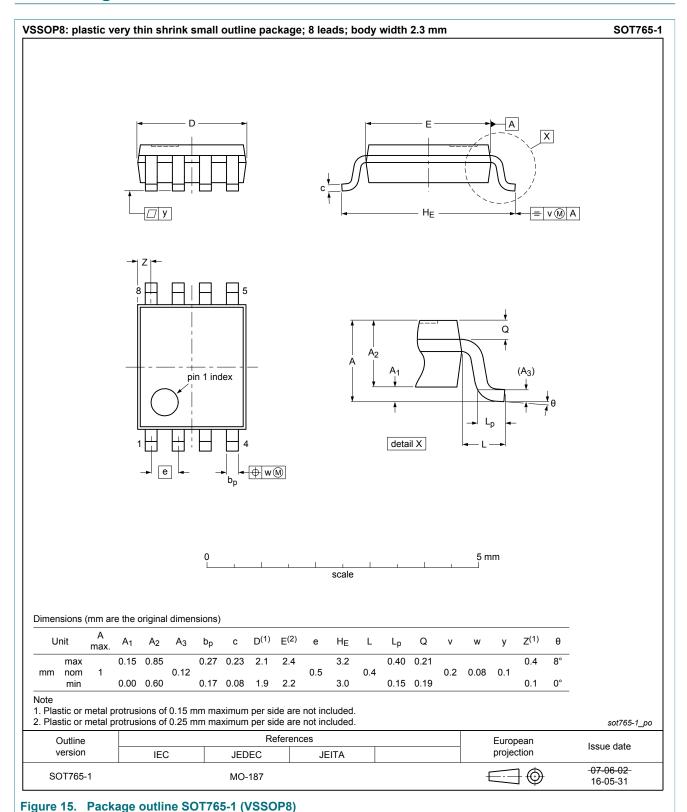


- (1) Positive-going edge
- (2) Negative-going edge

Linear change of V_I between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

Figure 14. Average I_{CC} as a function of V_{CC}

15 Package outline



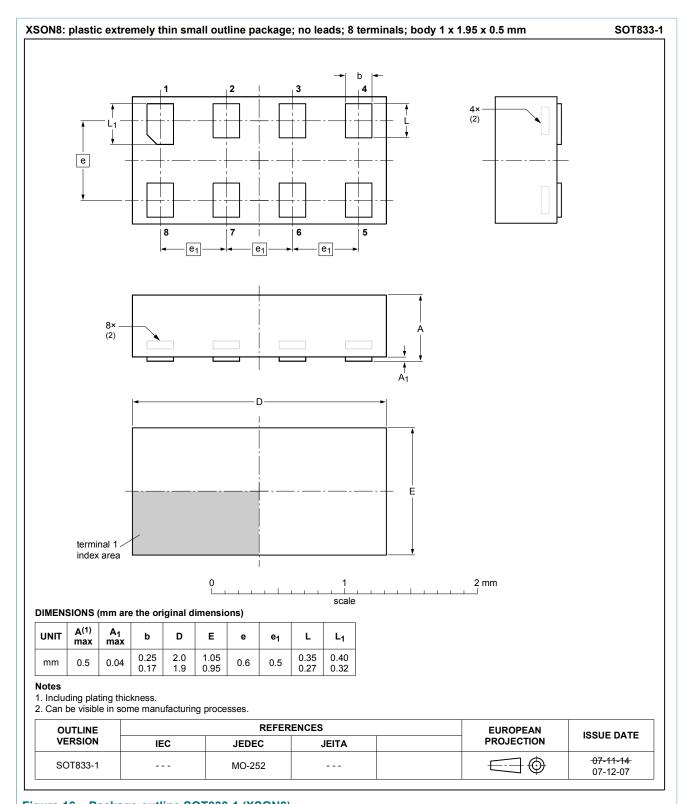
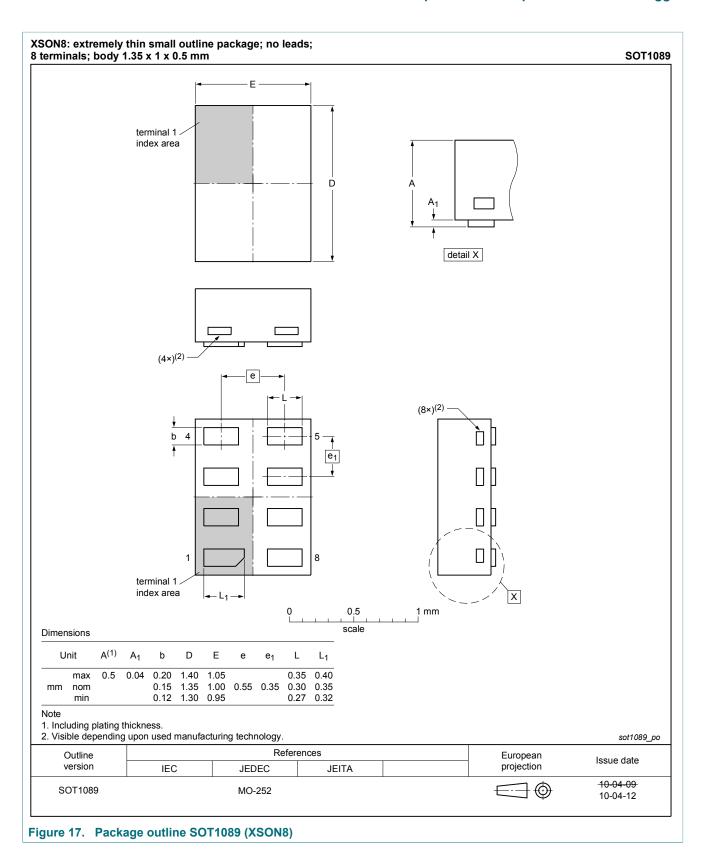
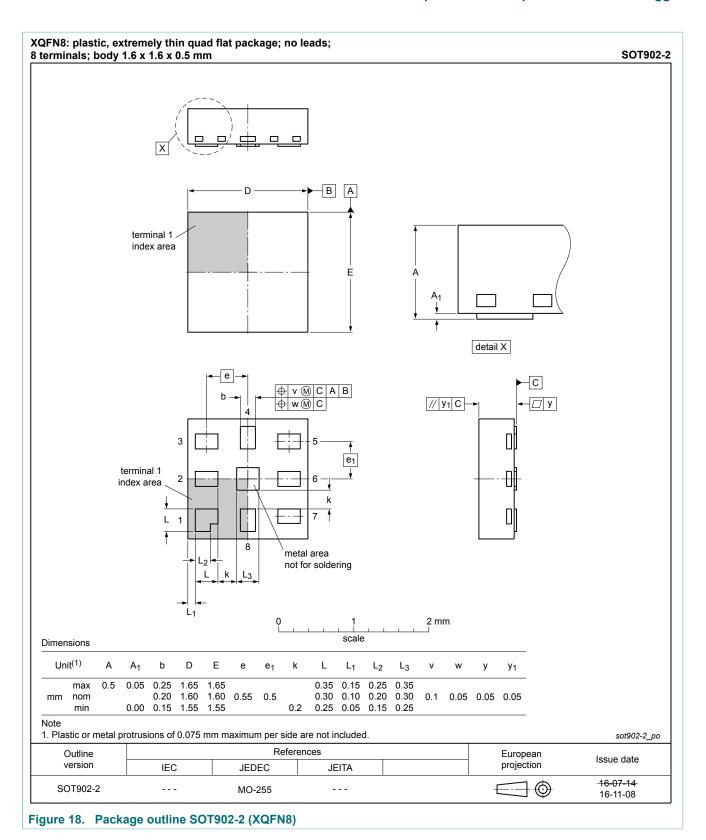


Figure 16. Package outline SOT833-1 (XSON8)



74AUP2G132



74AUP2G132

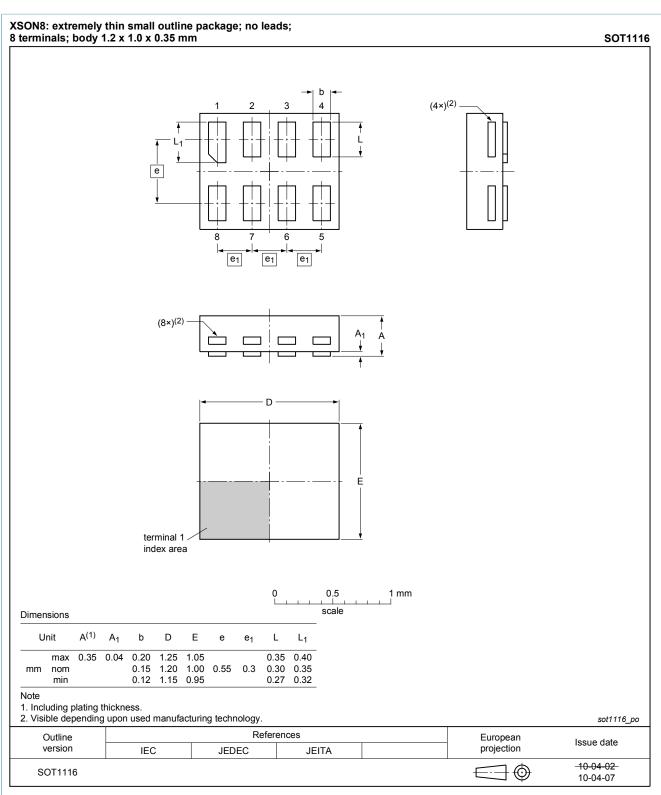
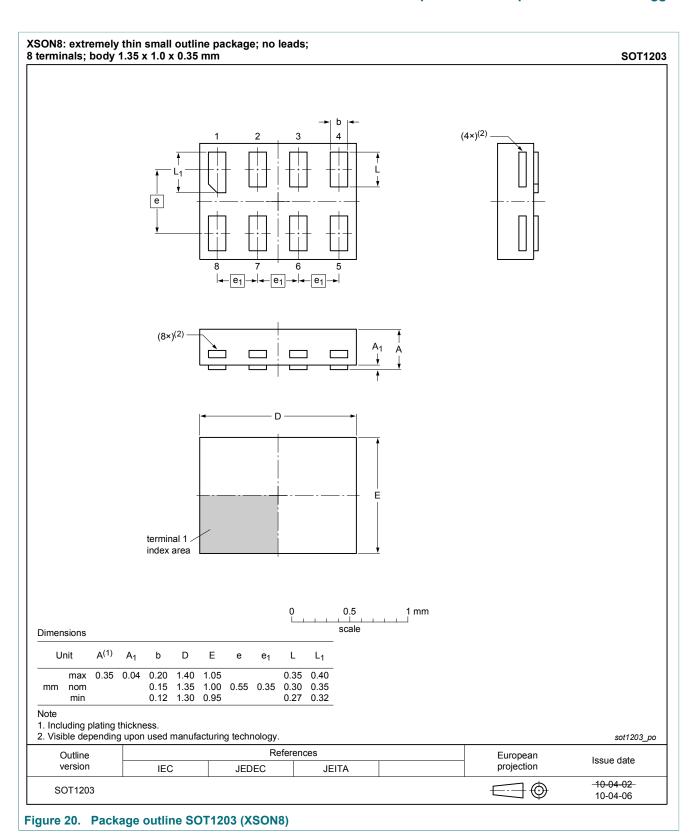
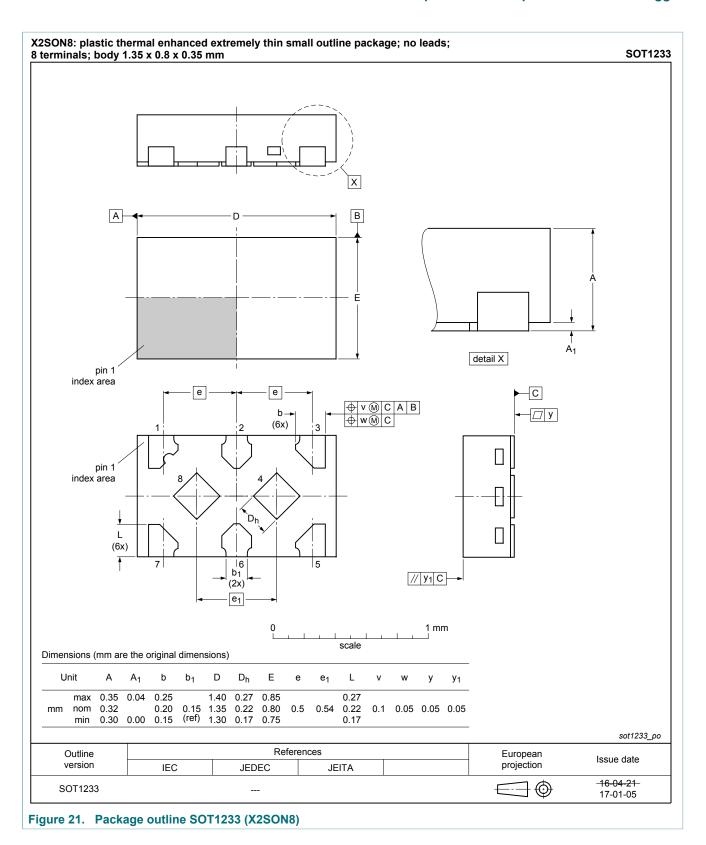


Figure 19. Package outline SOT1116 (XSON8)



74AUP2G132



74AUP2G132

16 Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

17 Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP2G132 v.8	20170703	Product data sheet	-	74AUP2G132 v.7			
Modifications:	Nexperia. • Legal texts hav • Type number 7	The fermial of the data enect has been reasonable to semply with the lastitly guidelines of					
74AUP2G132 v.7	20130208	Product data sheet	-	74AUP2G132 v.6			
Modifications:	For type number	For type number 74AUP2G132GD XSON8U has changed to XSON8.					
74AUP2G132 v.6	20120803	Product data sheet	-	74AUP2G132 v.5			
74AUP2G132 v.5	20111201	Product data sheet	-	74AUP2G132 v.4			
74AUP2G132 v.4	20101104	Product data sheet	-	74AUP2G132 v.3			
74AUP2G132 v.3	20081215	Product data sheet	-	74AUP2G132 v.2			
74AUP2G132 v.2	20080314	Product data sheet	-	74AUP2G132 v.1			
74AUP2G132 v.1	20061018	Product data sheet	-	-			

18 Legal information

18.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions". [2] [3]
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